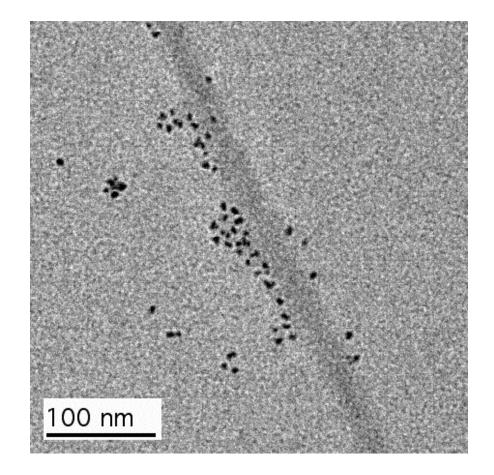


# Example: Cellulose + CdSe NPs



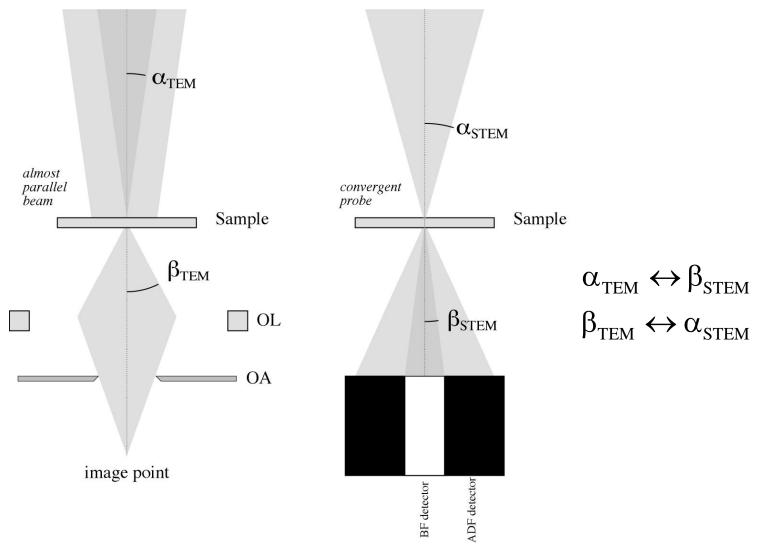
#### Mass-Thickness Contrast

- Primary contrast mechanism for amorphous materialsIncoherent, elastic scattering
- •Enhance by: 1) staining, 2) smaller objective aperture

$$I(T) = I_0 e^{-\mu T}$$
$$\mu = \frac{N_0 \cdot \rho \cdot \sigma_0}{A}$$
$$\mu T = \left(\frac{N_0 \sigma_0}{A}\right) \cdot (\rho T)$$

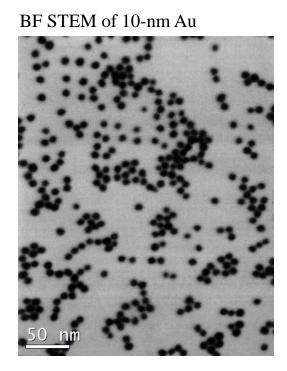
 $\rho T$ : mass-thickness (g/cm<sup>2</sup>)

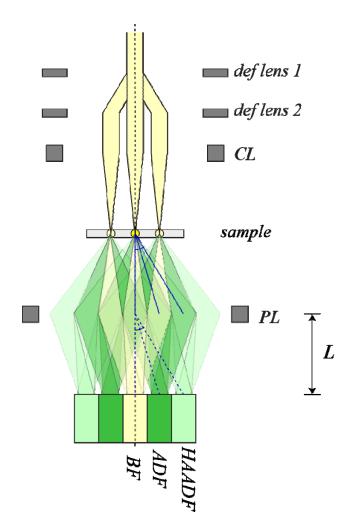
## Theorem of reciprocity



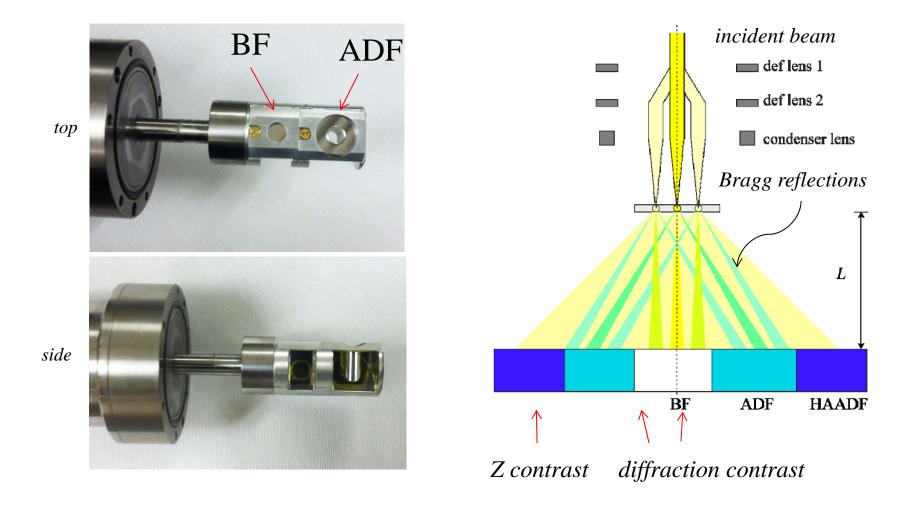
STEM image contrast is related to TEM image contrast

- •No significant post-specimen focusing in STEM
- •Eliminates post-specimen chromatic aberration
- •Bright-field and annular dark-field detectors
- •Photomultipliers or solid-state detectors





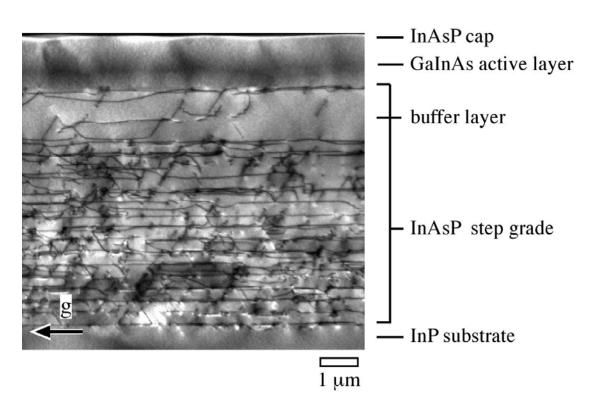
### **Retractable STEM detector**



### **Diffraction Contrast**

Nearly always contributes to images of crystalline materialsCoherent, elastic scattering

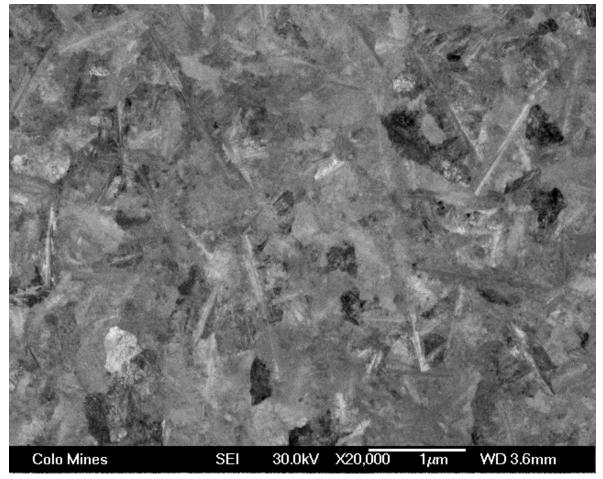
Useful to image: •Dislocations/defects •Chemical interfaces •Structural phases



For crystalline materials, always show the direction of **g** 

## STEM in an SEM

#### STEM Image of Recrystallized Si



#### Acquired in an SEM (with STEM detector)!

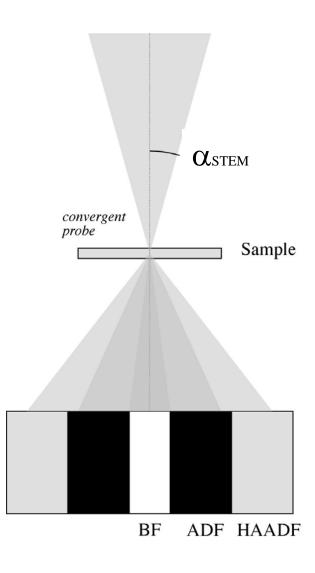
## Z-contrast imaging

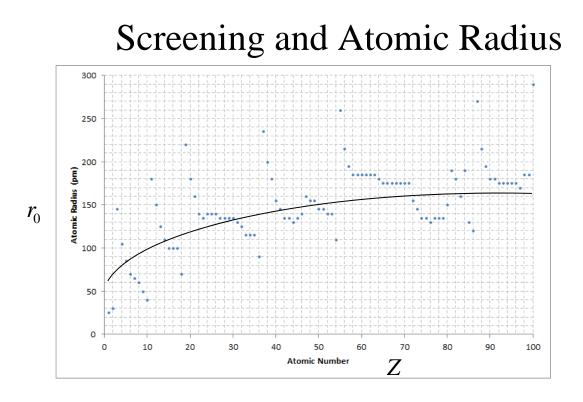
- •Uses a high-angle annular dark-field (HAADF) detector
- •Incoherent, elastic scattering
- •Eliminates diffraction contrast
- •Enhances chemical contrast
- •Best *not* to cool sample

$$\frac{d\sigma}{d\Omega}(\theta) = \left| f(\theta) \right|^2$$

$$f_{e}(\theta) = \frac{\lambda^{2} Z e^{2} m}{8\pi h^{2} \varepsilon_{0}} \cdot \left[\frac{1}{\sin^{2}(\theta/2) + \sin^{2}(\theta_{0}/2)}\right]$$

$$f_e(\theta) \propto \frac{Z}{\sin^2(\theta_0/2)}$$
 (low angle, screened)  
 $f_e(\theta) \propto \frac{Z}{\sin^2(\theta/2)}$  (high angle, unscreened)





http://en.wikipedia.org/wiki/Atomic\_radius#mediaviewer/File:Atomic\_number\_to\_radius\_graph.png

 $\varphi(r) = \frac{Ze}{4\pi\varepsilon_0 r} e^{-r/r_0}$  //Thomas-Fermi model for screened electrostatic potential of atom

$$4\pi\sin(\theta_0/2) = \frac{\lambda}{r_0} \qquad \qquad \lambda \ll r_0 \qquad \longrightarrow \qquad \qquad \theta_0 \approx \frac{\lambda}{2\pi r_0}$$

$$r_0 \approx \frac{a_B}{Z^{1/3}}$$
 //Wentzel atom model  $\longrightarrow \theta_0 \propto Z^{1/3} \longrightarrow f_e(\theta) \propto Z^{1/3}$  (low angle, screened)

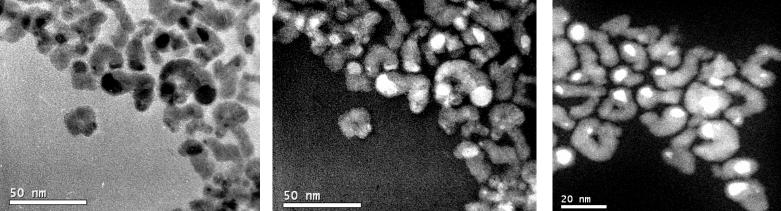
### HAADF examples

#### InAs Synthesized with Au Catalysts

Conventional BF

Inverted Contrast

HAADF



No diffraction contrast

#### GaAs/GaPAs QD superlattice "HAADF"

